









	<p>SQ3427EEV-T1-GE3</p>
	<p>Hersteller-Teilenummer: SQ3427EEV-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 60V 5.5A 6TSOP</p> <p>Datenblätter:  SQ3427EEV-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 40300 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SQ3427EEV-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 60V 5.5A 6TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	40300 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	5W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	5.5A (Tc)
Rds On (Max) @ Id, Vgs	82 mOhm @ 4.5A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	32nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1125pF @ 30V
Verpackung	Tape & Reel (TR)

SQ3427EEV-T1-GE3 ist neu im Original, Suche SQ3427EEV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SQ3427EEV-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SQ3427EEV-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SQ3427AEEV-T1_GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 60V 6TSOP</p>	 <p>SQ3426EV-T1_GE3 Vishay / Siliconix MOSFET N-CH 60V 7A 6-TSOP</p>	 <p>SQ3426EV-T1_GE3 Electro-Films (EFI) / Vishay MOSFET N-CHANNEL 60V 7A 6TSOP</p>	 <p>SQ3442EV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 4.3A 6TSOP</p>
 <p>SQ3427EV-T1-GE3 Vishay Precision Group SQ3427EV-T1-GE3 VISHAY</p>	 <p>SQ3427EEV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 60V 5.5A 6TSOP</p>	 <p>SQ3427AEEV-T1_GE3 Vishay / Siliconix MOSFET P-CH 60V 6TSOP</p>	 <p>SQ3427EV SCR SQ3427EV SCR</p>

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| ADG3231BRJ | AUR9705AGD | BA50BCOFP-E2 | BZT55C18-GS08 | CGA3E2C0G2A070D080AD |
| EPM3032ATC44-4N | ISL24826IRZ-T13 | K7N803601B-PC16 | LAS100-TP/SP3 | LM201AVDR2 |
| LQG15HS2N2J02D | PESD24VL1BA | PM30CVL060 | RB400VA-50TR | RB521ZS-3AZT2R |
| RT9742GGJ5 | SCE200AA160 | SI4654DY-T1-E3 | SM6S14A-E3/2D | SQ3410EV-T1-GE3 |
| SQ3418EEV-T1-GE3 | SQ3418EEV-T1-GE3 | SQ3418EV-T1-GE3 | SQ3419EEV-T1-GE3 | SQ3419EEV-T1-GE3 |
| SQ3419EV-T1-GE3 | SQ3425EV-T1-GE3 | SQ3426EEV-T1-GE3 | SQ3426EEV-T1-GE3 | SQ3426EV-T1-GE3 |
| SQ3427EEV-T1-GE3 | SQ3427EV | SQ3427EV-T1-GE3 | SQ3442EV-T1-GE3 | SQ3442EV-T1-GE3 |
| SQ3456BES-T1-GE3 | SQ3456BEV-T1-GE3 | SQ3456EV-T1-GE3 | SQ3457EV-T1-GE3 | SQ3457KGD |
| SQ3460EV-T1-GE3 | SQ3461EV-T1-GE3 | SQ3469EV-T1-GE3 | SQ3481EV-T1-GE3 | SQ3985EV-T1-GE3 |
| SQ3987EV-T1-GE3 | SQ3989EV-T1-GE3 | SS495A-SP | STD5NM60N-1 | TT162N1000KOF |

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